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Kind regards,

Team Nexperia

# 1PS76SB21; BAT721 series

## Schottky barrier diodes in small packages

Rev. 06 — 21 December 2006

**Product data sheet** 

### 1. Product profile

### 1.1 General description

Planar Schottky barrier diodes with an integrated guard ring for stress protection. Encapsulated in small Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package		Configuration
	NXP	JEITA	
1PS76SB21	SOD323	SC-76	single
BAT721	SOT23	-	single
BAT721A	SOT23	-	dual common anode
BAT721C	SOT23	-	dual common cathode
BAT721S	SOT23	-	dual series

#### 1.2 Features

- Low forward voltage
- Small SMD plastic packages
- Low capacitance

### 1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Line termination
- Reverse polarity protection

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
l <sub>F</sub>	forward current		-	-	200	mA
$V_{R}$	reverse voltage		-	-	40	V
V <sub>F</sub>	forward voltage	$I_F = 200 \text{ mA}$	[1] -	-	550	mV

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 



### 2. Pinning information

Table 3. **Pinning** Pin **Description** Simplified outline **Symbol** 1PS76SB21 [1] 1 cathode 1 - 2 2 anode sym001 **BAT721** anode 3 2 not connected 3 cathode n.c. 2 006aaa144 **BAT721A** cathode (diode 1) 3 2 cathode (diode 2) 3 anode (diode 1), anode (diode 2) 006aaa439 1 2 006aaa144 **BAT721C** 1 anode (diode 1) 3 2 anode (diode 2) 3 cathode (diode 1), cathode (diode 2) 006aaa438 2 006aaa144 **BAT721S** 1 anode (diode 1) 3 2 cathode (diode 2) 3 cathode (diode 1), anode (diode 2) 006aaa437 2 1 006aaa144

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<sup>[1]</sup> The marking bar indicates the cathode.

### 3. Ordering information

Table 4. Ordering information

Type number	Package					
	Name	Description	Version			
1PS76SB21	SC-76	plastic surface-mounted package; 2 leads	SOD323			
BAT721	-	plastic surface-mounted package; 3 leads	SOT23			
BAT721A						
BAT721C						
BAT721S						

### 4. Marking

Table 5. Marking codes

Type number	Marking code[1]
1PS76SB21	S1
BAT721	L7*
BAT721A	L8*
BAT721C	L9*
BAT721S	L0*

<sup>[1] \* = -:</sup> made in Hong Kong

### 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
$V_{R}$	reverse voltage		-	40	V
I <sub>F</sub>	forward current		-	200	mA
I <sub>FSM</sub>	non-repetitive peak forward current	half sine wave; JEDEC method; $t_p = 8.3 \text{ ms}$	-	1	Α
T <sub>j</sub>	junction temperature		-	125	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

### 6. Thermal characteristics

Table 7. Thermal characteristics

Table 1.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per diode							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]				
	1PS76SB21			-	-	450	K/W
	BAT721			-	-	500	K/W
	BAT721A			-	-	500	K/W
	BAT721C			-	-	500	K/W
	BAT721S			-	-	500	K/W

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

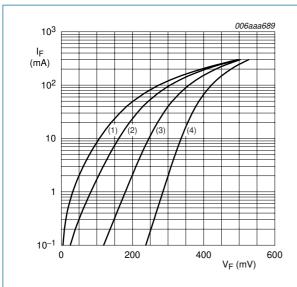
### 7. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

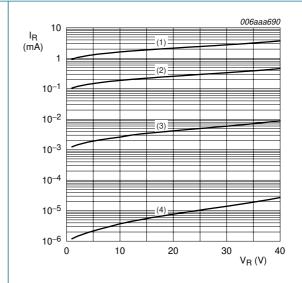
u		•				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
$V_{F}$	forward voltage	$I_F = 10 \text{ mA}$	<u>[1]</u> _	-	300	mV
		I <sub>F</sub> = 100 mA	<u>[1]</u> _	-	420	mV
		I <sub>F</sub> = 200 mA	<u>[1]</u> _	-	550	mV
I <sub>R</sub>	reverse current	$V_R = 30 \text{ V}$	-	-	15	μΑ
		$V_R = 30 \text{ V}; T_j = 100 ^{\circ}\text{C}$	-	-	3	mA
C <sub>d</sub>	diode capacitance	$V_R = 0 V; f = 1 MHz$	-	40	50	рF

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .



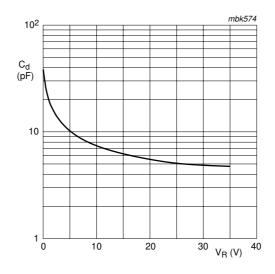
- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$
- (4)  $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$
- (4)  $T_{amb} = -40 \, ^{\circ}C$

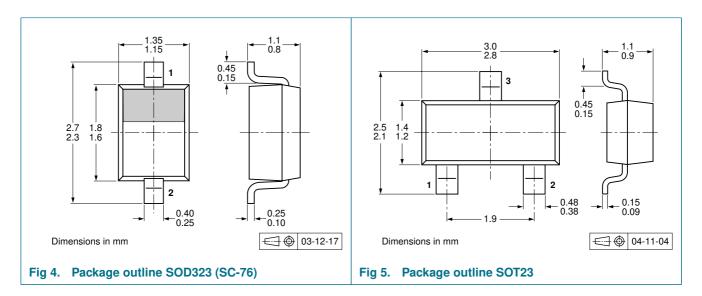
Fig 2. Reverse current as a function of reverse voltage; typical values



 $T_{amb} = 25 \,^{\circ}\text{C}; f = 1 \, \text{MHz}$ 

Fig 3. Diode capacitance as a function of reverse voltage; typical values

### 8. Package outline



### 9. Packing information

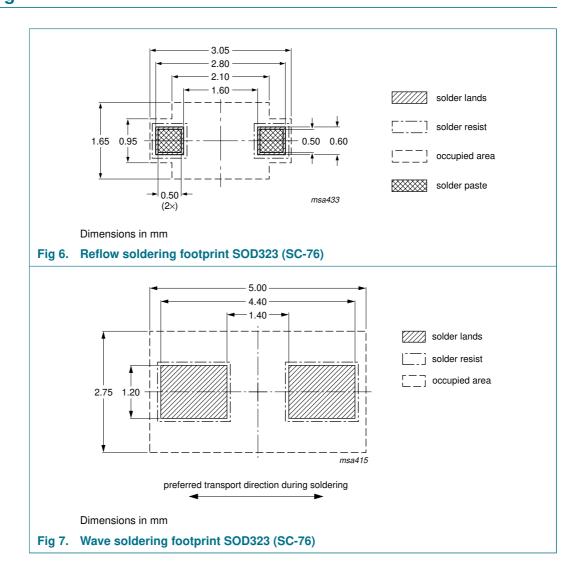
Table 9. Packing methods

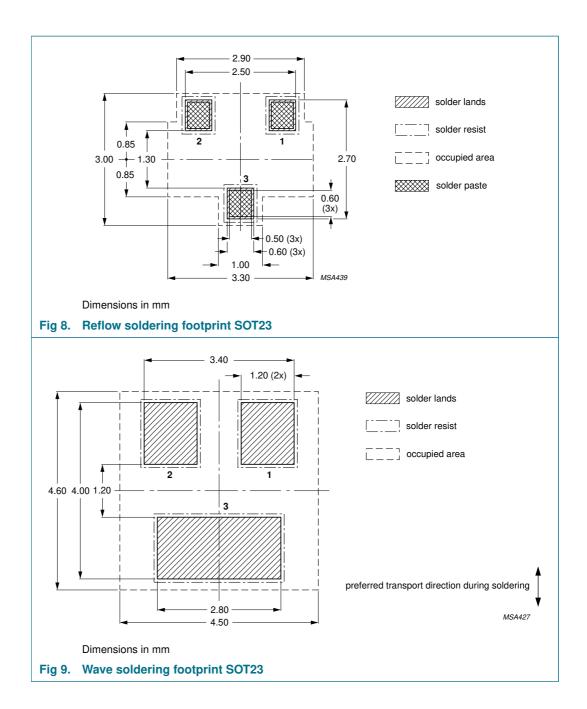
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	Packing quantity		
			3000	10000		
1PS76SB21	SOD323	4 mm pitch, 8 mm tape and reel	-115	-135		
BAT721	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235		
BAT721A						
BAT721C						
BAT721S						

[1] For further information and the availability of packing methods, see Section 13.

### 10. Soldering





# 1PS76SB21; BAT721 series

Schottky barrier diodes in small packages

## 11. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
1PS76SB21_BAT721_SER_6	20061221	Product data sheet	-	1PS76SB21_BAT721 _SER_5
Modifications:	<ul> <li>Amended <u>Ta</u></li> </ul>	ble 10 "Revision history"		
1PS76SB21_BAT721_SER_5	20061205	Product data sheet	-	BAT721_SERIES_4 1PS76SB21_3
Modifications:		of this data sheet has been render NXP Semiconductors.	edesigned to comply	with the new identity
	<ul> <li>Legal texts h</li> </ul>	ave been adapted to the ne	w company name who	ere appropriate.
	<ul> <li>This data she</li> <li>1PS76SB21</li> </ul>	eet is a combination of data _3.	sheets BAT721_SER	IES_4 and
	• Table 1 "Prod	duct overview": added		
	<ul> <li>Section 1.2 **</li> </ul>	Features": amended		
	<ul> <li>Section 1.3 **</li> </ul>	Applications": amended		
	<ul> <li>Table 2 "Quid</li> </ul>	ck reference data": added		
	<ul> <li>Table 5 "Mar</li> </ul>	king codes": for 1PS76SB2	1 amended	
	<ul> <li>Table 5 "Mar</li> </ul>	king codes": enhanced table	e note section	
	• Table 6 "Limi	iting values": indication per	diode added	
	• Table 6 "Limi	iting values": for 1PS76SB2	1 I <sub>FSM</sub> condition amen	ded
	• Table 6 "Limi	iting values": T <sub>amb</sub> ambient t	emperature added	
	• Table 7 "The	rmal characteristics": indica	tion per diode added	
	• Table 7: R <sub>th(j</sub>	<sub>-a)</sub> thermal resistance from j	unction to ambient co	ndition amended
	• Table 8 "Cha	racteristics": indication per	diode added	
	• Table 8 "Cha	racteristics": reference to Ta	able note 1 amended	
	• <u>Table 8</u> : for 1	PS76SB21 C <sub>d</sub> minimum va	lue changed to typical	value
	• Figure 1 and	2: amended		
	• Figure 4 and	5: superseded by minimize	d package outlines	
	Section 9 "Page 1.5"	acking information": added		
	Section 10 "S	Soldering": added		
	Section 12 "I	<u>_egal information"</u> : updated		
BAT721_SERIES_4	20040315	Product specification	-	BAT721_SERIES_3
1PS76SB21_3	20040126	Product specification	-	1PS76SB21_2

## 1PS76SB21; BAT721 series

Schottky barrier diodes in small packages

### 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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### **NXP Semiconductors**

# 1PS76SB21; BAT721 series

Schottky barrier diodes in small packages

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